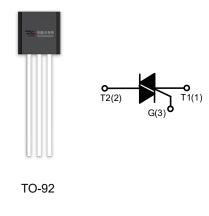


### **DESCRIPTION:**

The Z0103MA SCR series with the parallel resistor between Gate and Cathode are especially recommended for use on straight hair, igniter, anion generator, etc.

### **MAIN FEATURES**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	1	А
Ітѕм	16	А
V <sub>TM</sub>	≤1.5	V



### **ABSOLUTE MAXIMUM RATINGS**

Parameter		Symbol	Value	Unit
Storage junction temperature range		T <sub>stg</sub>	-40 - 150	$^{\circ}$ C
Operating junction temperature range		Tj	-40 - 125	$^{\circ}$ C
Repetitive peak off-state voltage (T <sub>j</sub> =25℃)		VDRM	600/800	V
Repetitive peak reverse voltage (T <sub>j</sub> =25℃)		VRRM	600/800	V
Non repetitive surge peak off-state voltage		VDSM	V <sub>DRM</sub> + 100	V
Non repetitive peak reverse voltage		VRSM	V <sub>RRM</sub> + 100	V
RMS on-state current	TO-92 (Tc=50°C)	I <sub>T(RMS)</sub>	1	А
Non repetitive surge peak on-state current (full cycle, F=50Hz)		Ітѕм	16	А
I <sup>2</sup> t value for fusing (tp=10ms)		l <sup>2</sup> t	1.28	A <sup>2</sup> s
Critical rate of rise of on-state current (I <sub>G</sub> =2×I <sub>GT</sub> )		dl/dt	20	A/µs
Peak gate current		Ідм	2	Α
Average gate power dissipation		P <sub>G(AV)</sub>	0.5	W
Peak gate power		P <sub>GM</sub>	5	W



# **ELECTRICAL CHARACTERISTICS** (T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Test Condition Qua	Ouedrant	Overdrept	Value		I I to i 4
		Quadrant		Т	D	Unit
lgт		I - II -III	MAX	5	5	mA
	V <sub>D</sub> =12V R <sub>L</sub> =33Ω	IV		5	10	
V <sub>G</sub> T		ALL	MAX	1.3		V
V <sub>GD</sub>	$V_D=V_{DRM}T_j=125$ °C RL=3.3KΩ	ALL	MIN	0.2		V
IL	I <sub>G</sub> =1.2I <sub>GT</sub>	I -III	MAX	5	5	mA
		II -IV		10	20	
Ін	I <sub>T</sub> =200mA		MAX	5	7	mA
dV/dt	V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125℃		MIN	15	20	V/µs

### **STATIC CHARACTERISTICS**

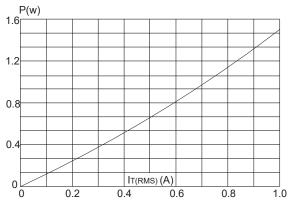
Symbol	Parameter		Value(MAX)	Unit
V <sub>TM</sub>	I <sub>тм</sub> =1.4A tp=380µs	T <sub>j</sub> =25℃	1.5	V
I <sub>DRM</sub>	VD=VDRM VR=VRRM	T <sub>j</sub> =25℃	5	μA
I <sub>RRM</sub>		Tj=125℃	500	μA

## **THERMAL RESISTANCES**

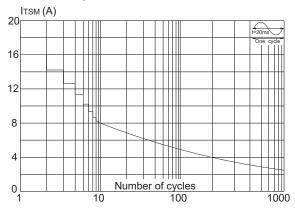
Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	junction to case(AC)	TO-92	60	°C/W



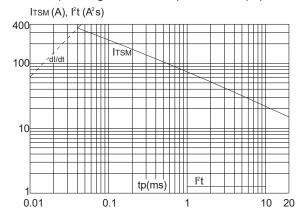
**FIG.1:** Maximum power dissipation versus RMS on-state current



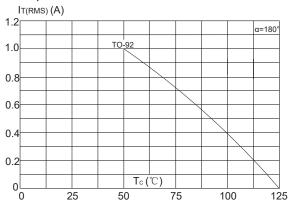
**FIG.3:** Surge peak on-state current versus number of cycles



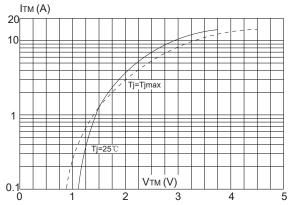
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<20ms and corresponding value of I<sup>2</sup>t (dl/dt < 20A/µs)



**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

